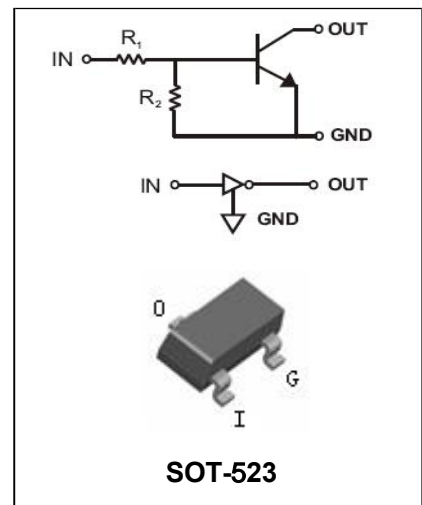


Digital Transistor

DTC(R₁=R₂ SERIES)E

FEATURES

- Epitaxial planar die construction.
- Complementary PNP types available(DTA).
- Built-in biasing resistors,R₁=R₂.
- Also available in lead free version.



APPLICATIONS

- The NPN style digital transistor.

ORDERING INFORMATION

Type No.	Marking	Package Code
DTC114EE	24	SOT-523
DTC124EE	25	SOT-523
DTC143EE	23	SOT-523
DTC144EE	26	SOT-523
DTC115EE	29	SOT-523

MAXIMUM RATING @ Ta=25°C unless otherwise specified

Symbol	Parameter	Value	Units	
V _{CC}	Supply Voltage	50	V	
V _{IN}	Input Voltage	DTC114EE DTC124EE DTC143EE DTC144EE DTC115EE	-10 to+40 -10 to+40 -10 to+30 -10 to+40 -10 to +40	V
I _O	Output Current	DTC114EE DTC124EE DTC143EE DTC144EE DTC115EE	50 30 100 30 100	mA
I _C (Max.)	Output current	ALL	100	mA
P _D	Power Dissipation		150	mW
R _{θJA}	Thermal Resistance, Junction to Ambient Air *1		306	°C/W
R _{θJC}	Thermal Resistance, Junction to Case *1		152	°C/W
R _{θJL}	Thermal Resistance, Junction to Lead *1		61	°C/W
T _J , T _{STG}	Operating and Storage and Temperature Range		-55 to +150	°C



Digital Transistor

DTC(R₁=R₂ SERIES)E

ELECTRICAL CHARACTERISTICS @ Ta=25°C unless otherwise specified

Parameter	Symbol	Test conditions	MIN	TYP	MAX	UNIT
Input Voltage	$V_{I(off)}$	$V_{CC}=5V, I_o=100\mu A$	0.5	-	-	V
Input Voltage	DTC114EE	$V_o=0.3V, I_o=10mA$	-	-	3	
	DTC124EE	$V_o=0.2V, I_o=5mA$				
	DTC143EE	$V_o=0.3V, I_o=20mA$				
	DTC144EE	$V_o=0.3V, I_o=2mA$				
	DTC115EE	$V_o=0.3V, I_o=1mA$				
Output Voltage	DTC114EE	$I_b/I_i=10mA/0.5mA$	-	-	0.3	V
	DTC124EE	$I_b/I_i=10mA/0.5mA$				
	DTC143EE	$I_b/I_i=10mA/0.5mA$				
	DTC144EE	$I_b/I_i=10mA/0.5mA$				
	DTC115EE	$I_b/I_i=5mA/0.25mA$				
Input Current	DTC114EE	$V_i=5V$	-	-	0.88	mA
	DTC124EE				0.36	
	DTC143EE				1.8	
	DTC144EE				0.18	
	DTC115EE				0.15	
Output Current	$I_{O(off)}$	$V_{CC}=50V, V_i=0V$	-	-	0.5	μA
DC Current Gain	DTC114EE	$V_o=5V, I_o=5mA$	30	-	-	-
	DTC124EE	$V_o=5V, I_o=5mA$	56			
	DTC143EE	$V_o=5V, I_o=10mA$	20			
	DTC144EE	$V_o=5V, I_o=5mA$	68			
	DTC115EE	$V_o=5V, I_o=5mA$	82			
Input Resistor	DTC114EE	$R_1(R_2)$	7	10	13	k Ω
	DTC124EE		15.4	22	28.6	
	DTC143EE		3.29	4.7	6.11	
	DTC144EE		32.9	47	61.1	
	DTC115EE		70	100	130	
Resistance Ratio	R_2/R_1	-	0.8	1	1.2	
Transition frequency	f_T	$V_o = 10V, I_o=5mA,$ $f=100MHz$	-	250	-	MHz

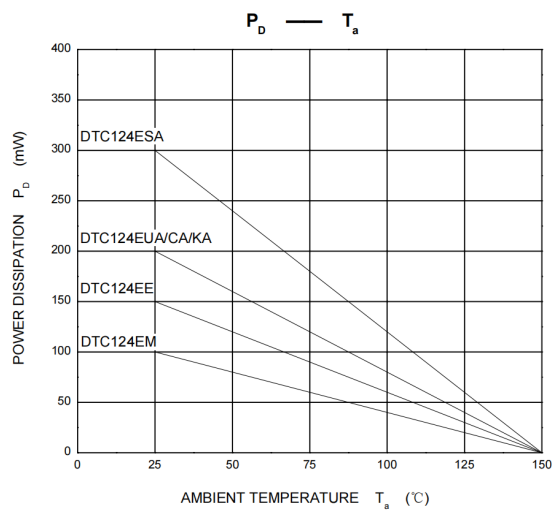
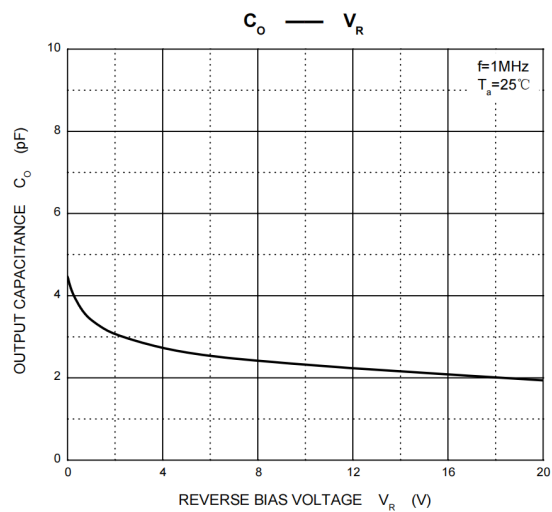
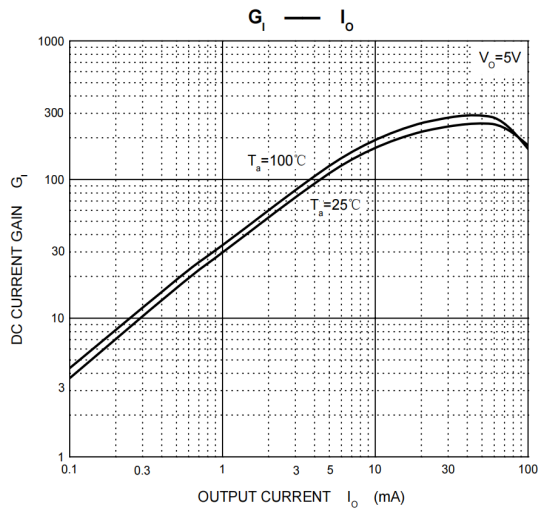
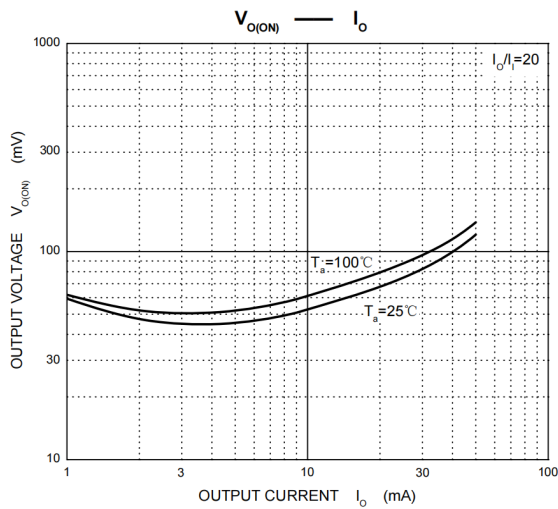
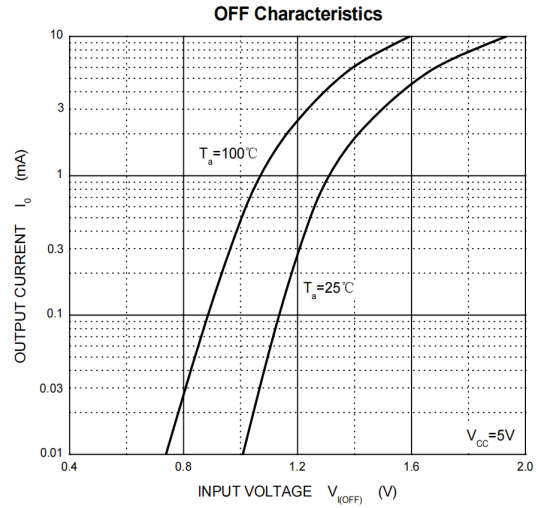
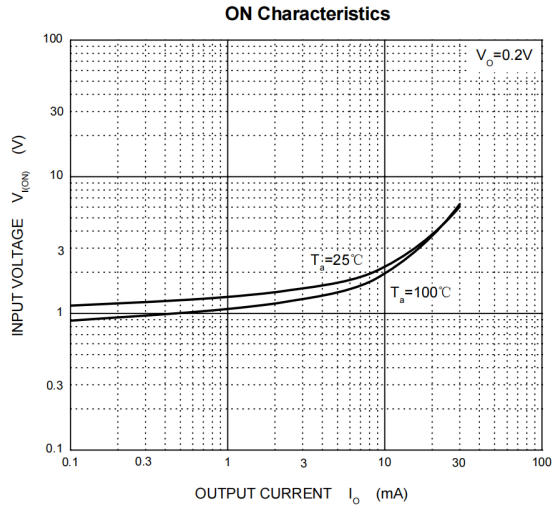
Note 1: The data tested by surface mounted on a 15mm * 15mm * 1mm FR4-epoxy P.C.B



Digital Transistor

DTC(R₁=R₂ SERIES)E

TYPICAL CHARACTERISTICS @ Ta=25°C unless otherwise specified



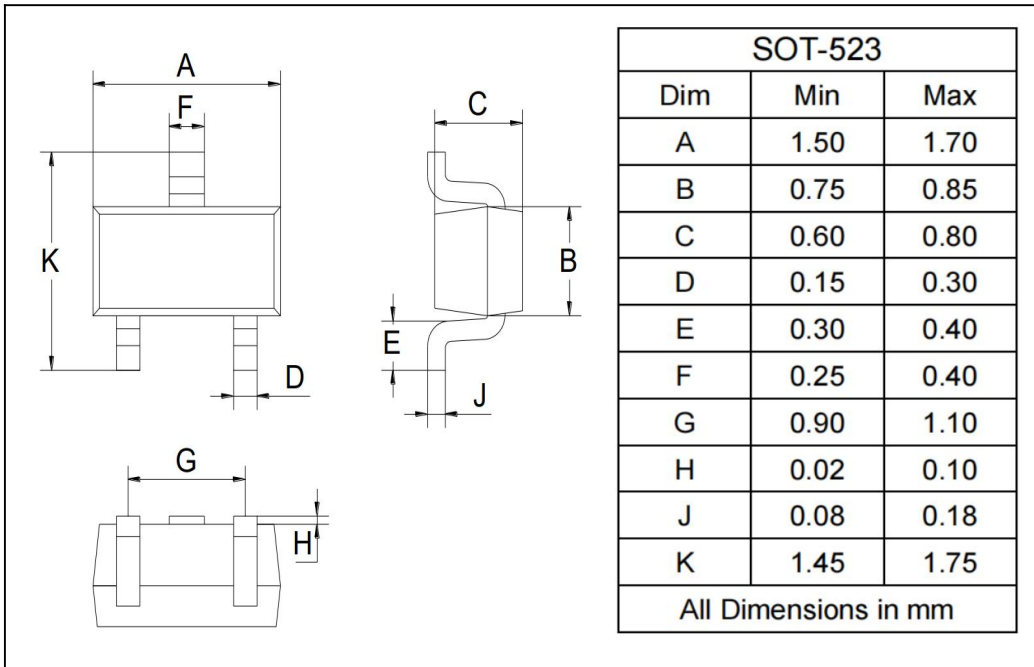
Digital Transistor

DTC(R₁=R₂ SERIES)E

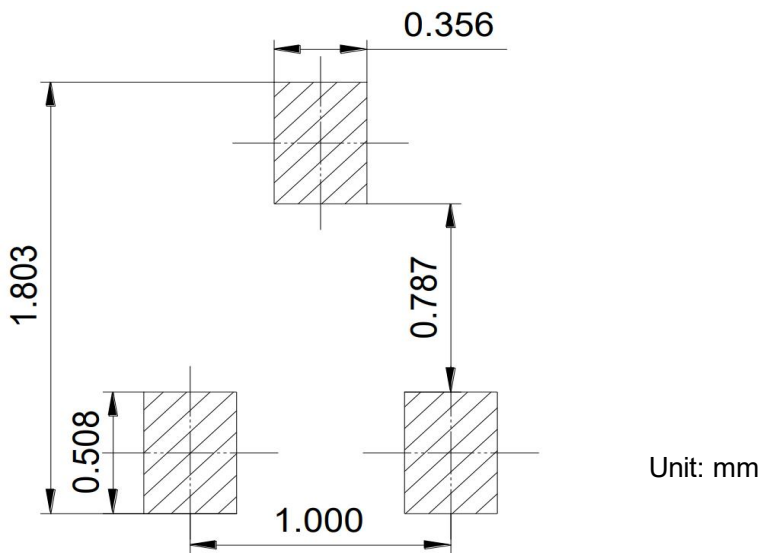
PACKAGE OUTLINE

Plastic surface mounted package

SOT-523



SOLDERING FOOTPRINT



PACKAGE INFORMATION

Device	Package	Shipping
DTC114EE/124EE/143EE/144EE/115EE	SOT-523	3000 pcs / Tape & Reel